# NSN 5961-00-485-5167

Transistor - Page 1 of 1



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#### Inclosure Material:

Metal

**Overall Length:** 

0.400 inches

# Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

0.437 inches

#### Thread Size:

0.190 inches

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 12.00 amperes source cutoff current

# Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector absolute

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

# Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

#### Fiig:

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